

## SMALL SIGNAL NPN TRANSISTORS

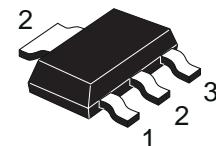
PRELIMINARY DATA

Ordering Code	Marking
BSP41	P41
BSP43	P43

- SILICON EPITAXIAL PLANAR PNP MEDIUM VOLTAGE TRANSISTORS
- SOT-223 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE AND REEL PACKING
- THE PNP COMPLEMENTARY TYPES ARE BSP31 AND BSP33 RESPECTIVELY

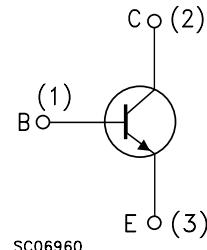
### APPLICATIONS

- MEDIUM VOLTAGE LOAD SWITCH TRANSISTORS
- OUTPUT STAGE FOR AUDIO AMPLIFIERS CIRCUITS
- AUTOMOTIVE POST-VOLTAGE REGULATION



SOT-223

### INTERNAL SCHEMATIC DIAGRAM



SC06960

### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		Unit
		BSP41	BSP43	
$V_{CBO}$	Collector-Base Voltage ( $I_E = 0$ )	70	90	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	60	80	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	5		V
$I_C$	Collector Current	1		A
$I_{CM}$	Collector Peak Current ( $t_p < 5 \text{ ms}$ )	2		A
$I_B$	Base Current	0.1		A
$I_{BM}$	Base Peak Current ( $t_p < 5 \text{ ms}$ )	0.2		A
$P_{tot}$	Total Dissipation at $T_{amb} = 25^\circ\text{C}$	1.3		W
$T_{stg}$	Storage Temperature	-65 to 150		$^\circ\text{C}$
$T_j$	Max. Operating Junction Temperature	150		$^\circ\text{C}$

## BSP41 BSR43

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### THERMAL DATA

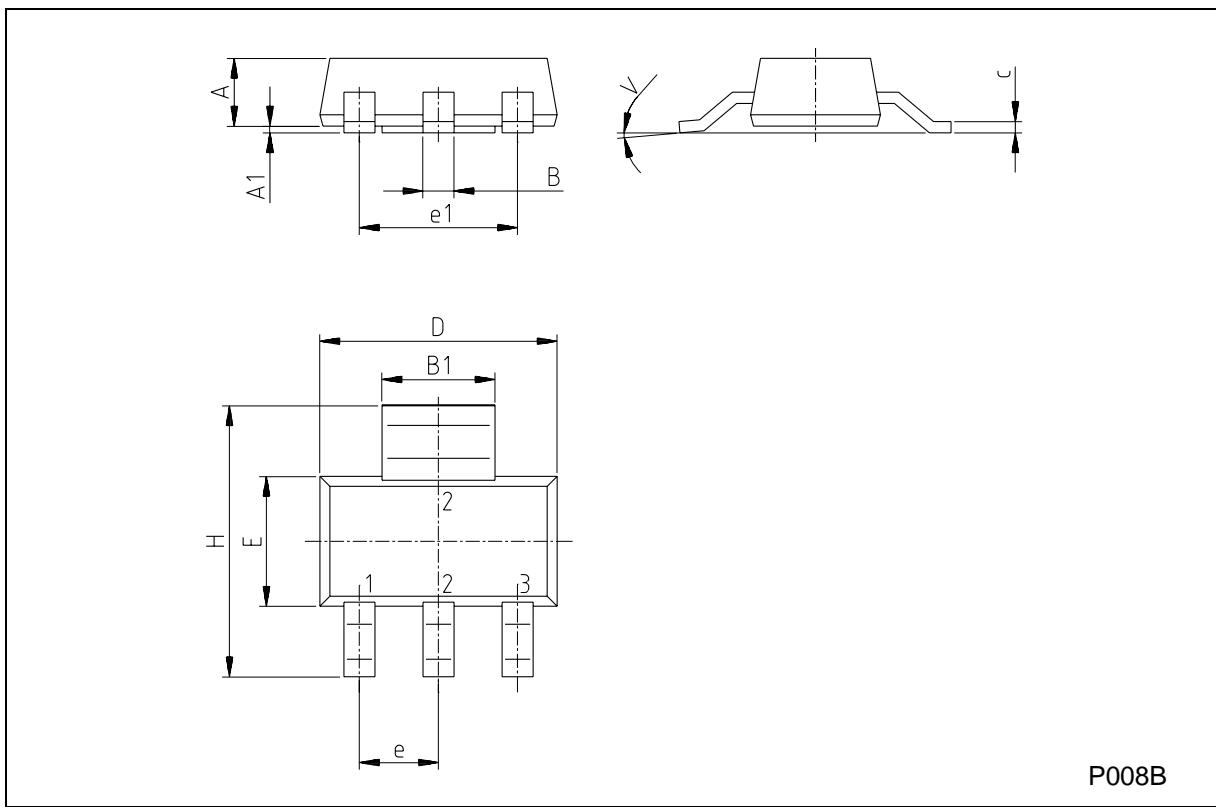
$R_{\text{thj-amb}}$ •	Thermal Resistance Junction-Ambient	Max	96.1	$^{\circ}\text{C/W}$
• Device mounted on a PCB area of 1 cm <sup>2</sup>				

### ELECTRICAL CHARACTERISTICS ( $T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{\text{CBO}}$	Collector Cut-off Current ( $I_E = 0$ )	$V_{\text{CB}} = 60 \text{ V}$ $V_{\text{CB}} = 60 \text{ V} \quad T_j = 150^{\circ}\text{C}$			100 50	nA $\mu\text{A}$
$I_{\text{EBO}}$	Emitter Cut-off Current ( $I_C = 0$ )	$V_{\text{EB}} = 5 \text{ V}$			100	nA
$V_{(\text{BR})\text{CBO}}$	Collector-Base Breakdown Voltage ( $I_E = 0$ )	$I_C = 100 \mu\text{A}$ for <b>BSP41</b> for <b>BSP43</b>	70 90			V V
$V_{(\text{BR})\text{CEO}}^*$	Collector-Emitter Breakdown Voltage ( $I_B = 0$ )	$I_C = 20 \text{ mA}$ for <b>BSP41</b> for <b>BSP43</b>	60 80			V V
$V_{(\text{BR})\text{EBO}}$	Emitter-Base Breakdown Voltage ( $I_C = 0$ )	$I_E = 10 \mu\text{A}$	5			V
$V_{\text{CE}(\text{sat})}^*$	Collector-Emitter Saturation Voltage	$I_C = 150 \text{ mA} \quad I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA} \quad I_B = 50 \text{ mA}$			0.25 0.5	V V
$V_{\text{BE}(\text{sat})}^*$	Base-Emitter Saturation Voltage	$I_C = 150 \text{ mA} \quad I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA} \quad I_B = 50 \text{ mA}$			1 1.2	V V
$h_{\text{FE}}^*$	DC Current Gain	$I_C = 100 \mu\text{A} \quad V_{\text{CE}} = 5 \text{ V}$ $I_C = 100 \text{ mA} \quad V_{\text{CE}} = 5 \text{ V}$ $I_C = 500 \text{ mA} \quad V_{\text{CE}} = 5 \text{ V}$	30 100 50		300	
$f_T$	Transition Frequency	$I_C = 50 \text{ mA} \quad V_{\text{CE}} = 10 \text{ V}$ $f = 100 \text{ MHz}$	100			MHz

\* Pulsed: Pulse duration = 300  $\mu\text{s}$ , duty cycle  $\leq 1.5\%$

SOT-223 MECHANICAL DATA						
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.80			0.071
B	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
c	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
e		2.30			0.090	
e1		4.60			0.181	
E	3.30	3.50	3.70	0.130	0.138	0.146
H	6.70	7.00	7.30	0.264	0.276	0.287
V			10°			10°
A1		0.02				



P008B

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